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## Spectroscopy images exotic electronic systems and experiences interplay between different emerging phenomena in Transition Metal Oxides

*Wednesday, 17 April 2024 16:15 (1h 30m)*

Transition Metal Oxides (TMOs) are known for their diverse and multifaceted physical behaviors, intricately linked to the spin and orbital configurations of transition metal d-states and their dynamic interaction with the crystal lattice [1]. A powerful strategy to modify the physical properties of TMOs originates from their structural flexibility, enabling the construction of heterostructures. Specifically, it will be exhibited that manipulating the electronic structures through TMO-engineered heterostructures [2] is a foundational step toward utilizing those materials in novel devices.

This lecture delves into significant revelations from Angle-Resolved Photoemission Spectroscopy (ARPES) concerning two topics:

- (I) Low-dimensional electronic systems (LDES) and,
- (II) Metal-Insulator Transition (MIT).

The first topic will concern how LDES in SrTiO<sub>3</sub> (STO) is influenced by the crystal structure, orbital ordering, and defects [3-5]. The second part of the lecture will specifically discuss how ARPES studies on RENiO<sub>3</sub> have shed light on the underlying mechanisms driving the MIT in complex oxides. [3]. Further, it will be examined how establishing the novel ferromagnetic order in thin NdNiO<sub>3</sub> (NNO) films, accomplished through heterostructures containing a magnetic layer, profoundly mitigates the MIT [4]. This example illustrates the capability to utilize magnetic interactions to influence the electronic states of TMOs.

The ARPES studies, in general, highlighted and emphasized the versatility of TMOs as quantum materials for future applications in advanced technology.

### References

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2. Pavlo Zubko, Stefano Gariglio, Marc Gabay, Philippe Ghosez, Jean-Marc Triscone, *Interface physics in complex oxides*
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4. AF Santander-Syro, F Fortuna, C Bareille, TC Rödel, G Landolt, NC Plumb, JH Dil, M Radović, *Giant spin splitting in NdNiO<sub>3</sub> thin films*
5. Eduardo B Guedes, Stefan Muff, Walber H Brito, Marco Caputo, Hang Li, Nicholas C Plumb, J Hugo Dil, Milan Radović
6. R. S. Dhaka, Tanmoy Das, N. C. Plumb, Z. Ristic, W. Kong, C. E. Matt, N. Xu, Kapildeb Dolui, E. Razzoli, M. Madsen
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